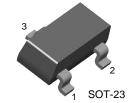


KSC1623

Low Frequency Amplifier & High Frequency OSC.

• Complement to KSA812



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

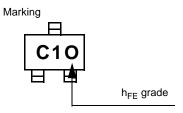
| Symbol | Parameter | Ratings | Units | |
|------------------|-----------------------------|-----------|-------|--|
| V _{CBO} | Collector-Base Voltage | 60 | V | |
| V _{CEO} | Collector-Emitter Voltage | 50 | V | |
| V _{EBO} | Emitter-Base Voltage | 5 | V | |
| I _C | Collector Current | 100 | mA | |
| P _C | Collector Power Dissipation | 200 | mW | |
| T _J | Junction Temperature | 150 | °C | |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C | |

Electrical Characteristics T_a =25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| I _{CBO} | Collector Cut-off Current | V_{CB} =60V, I_E =0 | | | 0.1 | μΑ |
| I _{EBO} | Emitter Cut-off Current | V_{EB} =5V, I_C =0 | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | $V_{CE}=6V, I_{C}=1mA$ | 90 | 200 | 600 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =100mA, I _B =10mA | | 0.15 | 0.3 | V |
| V _{BE} (sat) | Base-Emitter Saturation Voltage | I _C =100mA, I _B =10mA | | 0.86 | 1.0 | V |
| V _{BE} (on) | Base-Emitter On Voltage | $V_{CE}=6V, I_{C}=1mA$ | 0.55 | 0.62 | 0.65 | V |
| f _T | Current Gain Bandwidth Product | V_{CE} =6V, I_{C} =10mA | | 250 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} =6V, I _E =0, f=1MHz | | 3 | | pF |

h_{FE} Classification

| Classification | 0 | Y | G | L |
|-----------------|----------|-----------|-----------|-----------|
| h _{EE} | 90 ~ 180 | 135 ~ 270 | 200 ~ 400 | 300 ~ 600 |



Typical Characteristics

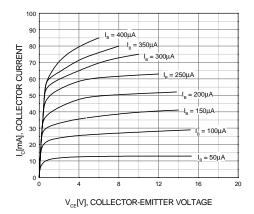


Figure 1. Static Charactersitic

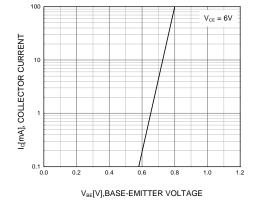


Figure 2. Transfer Characteristic

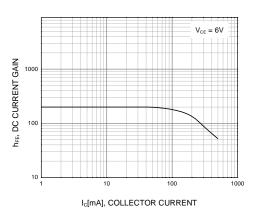


Figure 3. DC current Gain

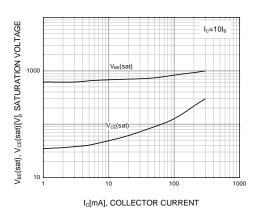


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

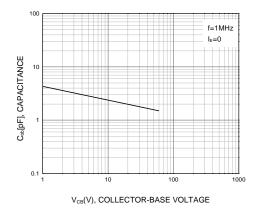


Figure 5. Output Capacitance

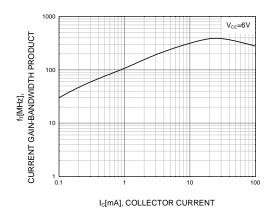


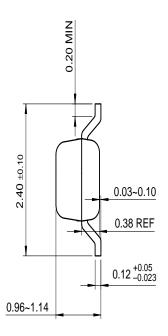
Figure 6. Current Gain Bandwidth Product

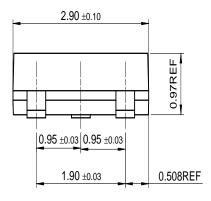
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Package Dimensions

SOT-23







Dimensions in Millimeters

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| CoolFET™ | FASTr™ | MicroFET™ | PowerTrench [®] | SuperSOT™-6 |
| CROSSVOLT™ | FRFET™ | MicroPak™ | QFET™ | SuperSOT™-8 |
| DOME™ | GlobalOptoisolator™ | MICROWIRE™ | QS^{TM} | SyncFET™ |
| EcoSPARK™ | GTO™ | MSX™ | QT Optoelectronics™ | TinyLogic™ |
| E ² CMOS™ | HiSeC™ | MSXPro™ | Quiet Series™ | TruTranslation™ |
| EnSigna™ | I^2C^{TM} | OCX^{TM} | RapidConfigure™ | UHC™ |
| Across the board. | . Around the world.™ | OCXPro™ | RapidConnect™ | UltraFET [®] |
| The Power Franchise™ | | OPTOLOGIC [®] | SILENT SWITCHER® | VCX^{TM} |
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